Features

- Low Noise Figure
- Excellent Input Return Loss
- Single Voltage Bias 3 V
- Integrated Active Bias Circuit
- Current Adjustable 20-80 mA with an External Resistor
- High Linearity, OIP3 > 34 dBm
- Small Package: 2 mm PDFN-8LD
- RoHS* Compliant and 260°C Reflow Compatible

Description

The MAAL-010706 is a high dynamic range single stage MMIC LNA with excellent linearity and low noise figure designed for operation from 1.4 to 4.0 GHz. The LNA is packaged in an RoHS compliant leadless 2 mm 8-lead PDFN package.

This MMIC has an integrated active bias circuit allowing direct connection to +3 V voltage supply and minimizing variation over temperature and process. The bias current and gain can be set with external resistors to allow the user to customize the current and gain value to fit the application.

The MAAL-010706 offers less than 0.7 dB noise figure, more than 34 dBm OIP3 and 20 dB input return loss. The excellent input match, low noise figure and high OIP3 along with the flexibility of setting current and gain make this LNA ideal for 3G and 4G cellular infrastructure applications.

For optimum performance below 1.4 GHz the MAAL-010705 is recommended. The MAAL-010706 and MAAL-010705 share the package type and footprint.

Functional Block Diagram

Pin Configuration

<table>
<thead>
<tr>
<th>Pin No.</th>
<th>Pin Name</th>
<th>Description</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>N/C</td>
<td>No Connection</td>
</tr>
<tr>
<td>2</td>
<td>RF_IN</td>
<td>RF Input</td>
</tr>
<tr>
<td>3</td>
<td>RF_GND</td>
<td>RF Ground</td>
</tr>
<tr>
<td>4</td>
<td>V_BIAS</td>
<td>Bias Voltage</td>
</tr>
<tr>
<td>5</td>
<td>FB</td>
<td>Feedback</td>
</tr>
<tr>
<td>6</td>
<td>N/C</td>
<td>No Connection</td>
</tr>
<tr>
<td>7</td>
<td>RF_OUT</td>
<td>RF Output</td>
</tr>
<tr>
<td>8</td>
<td>N/C</td>
<td>No Connection</td>
</tr>
</tbody>
</table>

Ordering Information

<table>
<thead>
<tr>
<th>Part Number</th>
<th>Package</th>
</tr>
</thead>
<tbody>
<tr>
<td>MAAL-010706-TR3000</td>
<td>tape and reel</td>
</tr>
<tr>
<td>MAAL-010706-001SMB</td>
<td>evaluation board</td>
</tr>
</tbody>
</table>

1. Reference Application Note M513 for reel size information.
2. All sample boards include 5 loose parts.

Low Noise Amplifier
1.4-4.0 GHz

Electrical Specifications: Freq = 1.85 GHz, Vd = 4 V, 25ºC, Z₀ = 50 Ω

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Test Conditions</th>
<th>Units</th>
<th>Min.</th>
<th>Typ.</th>
<th>Max.</th>
</tr>
</thead>
<tbody>
<tr>
<td>Gain</td>
<td></td>
<td>dB</td>
<td>16.0</td>
<td>17.5</td>
<td>-</td>
</tr>
<tr>
<td>Output IP3</td>
<td>Pout=5 dBm, Tone Spacing=1 MHz</td>
<td>dBm</td>
<td>-</td>
<td>34.5</td>
<td>-</td>
</tr>
<tr>
<td>Output P1dB</td>
<td></td>
<td>dBm</td>
<td>17.5</td>
<td>19</td>
<td>-</td>
</tr>
<tr>
<td>Input Return Loss</td>
<td></td>
<td>dB</td>
<td>-</td>
<td>21</td>
<td>-</td>
</tr>
<tr>
<td>Output Return Loss</td>
<td></td>
<td>dB</td>
<td>-</td>
<td>15</td>
<td>-</td>
</tr>
<tr>
<td>Noise Figure</td>
<td></td>
<td>dB</td>
<td>-</td>
<td>0.60</td>
<td>-</td>
</tr>
<tr>
<td>Total Current</td>
<td>IDQ=Id+IBias</td>
<td>mA</td>
<td>-</td>
<td>60</td>
<td>70</td>
</tr>
</tbody>
</table>

3. Vd and Vbias are connected together to +4 V, R3 = 300 ohms and R4 = 240 ohms, reference recommended schematic on page 8.

Absolute Maximum Ratings

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Absolute Max.</th>
</tr>
</thead>
<tbody>
<tr>
<td>Supply Voltage</td>
<td>+5.5 V</td>
</tr>
<tr>
<td>Current</td>
<td>100 mA</td>
</tr>
<tr>
<td>Power Dissipation</td>
<td>600 mW</td>
</tr>
<tr>
<td>RF Input Power</td>
<td>20 dBm</td>
</tr>
<tr>
<td>Storage Temperature</td>
<td>-55 to +150 ºC</td>
</tr>
<tr>
<td>Operating Temperature</td>
<td>-40 to +85 ºC</td>
</tr>
<tr>
<td>Junction Temperature</td>
<td>+150 ºC</td>
</tr>
</tbody>
</table>

4. Exceeding any one or combination of these limits may cause permanent damage to this device.
5. M/A-COM Technology Solutions does not recommend sustained operation near these survivability limits.
6. Typical thermal resistance (θjc) = 45 °C/W.

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these class 1A devices.
Typical Performance Curves: 4 V (over current)

Input Return Loss

Output Return Loss

Gain

Noise Figure

OIP3

P1dB
Low Noise Amplifier
1.4-4.0 GHz

Typical Performance Curves: 4 V (over R3)

**Gain**

![Gain Graph](image)

**Noise Figure & Fmin**

![Noise Figure Graph](image)

**OIP3**

![OIP3 Graph](image)

**P1dB**

![P1dB Graph](image)
Typical Performance Curves: 4 V (over temperature)

**Input Return Loss**

![Input Return Loss Graph]

**Output Return Loss**

![Output Return Loss Graph]

**Gain**

![Gain Graph]

**Noise Figure**

![Noise Figure Graph]

**OIP3**

![OIP3 Graph]

**P1dB**

![P1dB Graph]
Typical Performance Curves: 3 V

**Input Return Loss**

- For different values of Id (mA)
- Graph shows dB vs. F (GHz)

**Output Return Loss**

- For different values of Id (mA)
- Graph shows dB vs. F (GHz)

**Gain**

- For different values of Id (mA)
- Graph shows dB vs. F (GHz)

**Noise Figure**

- For different values of Id (mA)
- Graph shows NF (dB) vs. F (GHz)

**OIP3**

- For different values of Id (mA)
- Graph shows OIP3 (dBm) vs. F (GHz)

**P1dB**

- For different values of Id (mA)
- Graph shows P1dB vs. F (GHz)
S-Parameters\(^7\): 4 V

Reverse Isolation

Gain

Output Return Loss

Input Return Loss

7. S-Parameters files are available for download at macomtech.com.
V\textsubscript{BIAS} and V\textsubscript{D} are separate connections on the evaluation board to give the option of varying I\textsubscript{D} without changing R4. They can be connected together to a single voltage supply during the measurement and in the final layout implementation of the PCB. If two different voltage supplies are used then apply V\textsubscript{D} first and then V\textsubscript{BIAS} to turn on the LNA. To turn off the LNA disconnect V\textsubscript{BIAS} first and then V\textsubscript{D}. R3 is varied to obtain different levels of gain. R4 is varied to change the drain current I\textsubscript{D}.
**Lead-Free 2 mm 8-Lead PDFN†**

† Reference Application Note S2083 for lead-free solder reflow recommendations.
Meets JEDEC moisture sensitivity level 1 requirements.